RoHS

COMPLIANT

HALOGEN FREE



### Vishay General Semiconductor

# High Current Density Surface Mount MOS Barrier Schottky Rectifier Ultra Low

 $V_F = 0.453 \text{ V at } I_F = 5 \text{ A}$ 

### TMBS® eSMP® Series



#### SMPC (TO-277A)



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	10 A			
V <sub>RRM</sub>	100 V			
I <sub>FSM</sub>	180 A			
E <sub>AS</sub>	100 mJ			
V <sub>F</sub> at I <sub>F</sub> = 10 A	0.574 V			
T <sub>J</sub> max.	150 °C			
Package	TO-277A (SMPC)			
Diode variations	Diode variations Single die			

#### **FEATURES**

- Very low profile typical height of 1.1 mm
- · Ideal for automated placement
- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
  - Automotive ordering code; base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

#### **MECHANICAL DATA**

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3\_X - halogen-free, RoHS-compliant and

AEC-Q101 qualified

("\_X" denotes revision code e.g. A, B,....)

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

0-31D-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V10P10	UNIT	
Device marking code		V1010		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub> 100		V	
Maximum average forward rectified current (fig. 1)	I <sub>F(AV)</sub>	10	А	
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	180	А	
Non-repetitive avalanche energy at I <sub>AS</sub> = 2.0 A, T <sub>J</sub> = 25 °C	E <sub>AS</sub>	100	mJ	
Peak repetitive reverse current at $t_p$ = 2 $\mu$ s, 1 kHz, $T_J$ = 38 °C $\pm$ 2 °C	I <sub>RRM</sub>	1.0	А	
Operating junction temperature range	T <sub>J</sub> <sup>(1)</sup>	-40 to +175	°C	
Storage temperature range	T <sub>STG</sub>	-55 to +175	°C	

#### Note

 $<sup>^{(1)}</sup>$  The heat generated must be less than the thermal conductivity from junction to ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Breakdown voltage	I <sub>R</sub> = 1 mA	T <sub>A</sub> = 25 °C	$V_{BR}$	100 (minimum)	-	V
Instantaneous forward voltage	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.512	-	V
	I <sub>F</sub> = 10 A			0.625	0.68	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.453	-	
	I <sub>F</sub> = 10 A			0.574	0.62	
Reverse current	V <sub>R</sub> = 70 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	7.1	-	μΑ
	v <sub>R</sub> = 70 v	T <sub>A</sub> = 125 °C		4.5	-	mA
	V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C		30.4	150	μΑ
	v <sub>R</sub> = 100 v	T <sub>A</sub> = 125 °C		10.4	20	mA

#### Notes

 $^{(2)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

 $^{(3)}$  Pulse test: Pulse width  $\leq$  40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise specified)				
PARAMETER	SYMBOL	V10P10	UNIT	
Typical thermal resistance	R <sub>0JA</sub> (1)	60	°C/W	
	$R_{ heta JL}$	3		

#### Note

(1) Units mounted on recommended PCB 1 oz. pad layout

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
V10P10-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel	
V10P10-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel	
V10P10HM3_A/H <sup>(1)</sup>	0.10	Н	1500	7" diameter plastic tape and reel	
V10P10HM3_A/I <sup>(1)</sup>	0.10	I	6500	13" diameter plastic tape and reel	

#### Note

(1) AEC-Q101 qualified



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### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise specified)

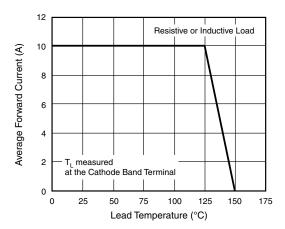


Fig. 1 - Maximum Forward Current Derating Curve

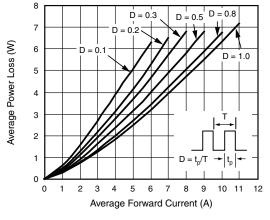


Fig. 2 - Forward Power Loss Characteristics

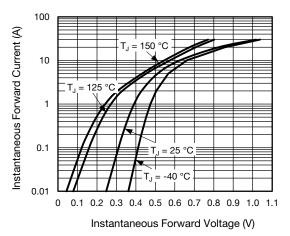


Fig. 3 - Typical Instantaneous Forward Characteristics

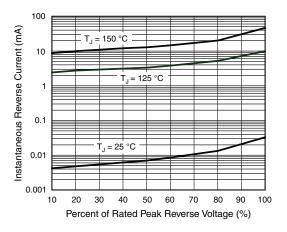


Fig. 4 - Typical Reverse Characteristics

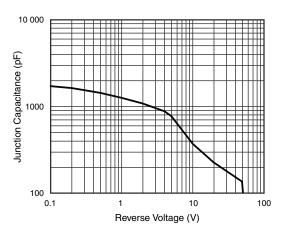


Fig. 5 - Typical Junction Capacitance

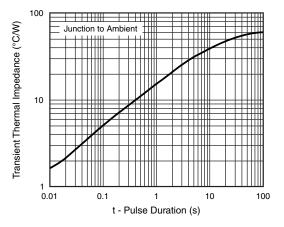
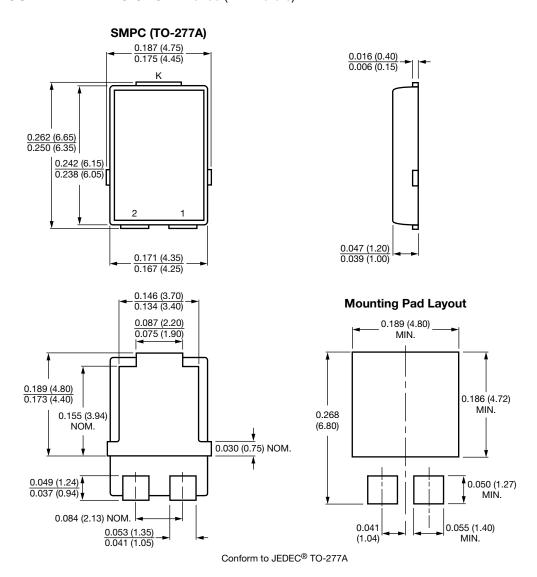


Fig. 6 - Typical Transient Thermal Impedance



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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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